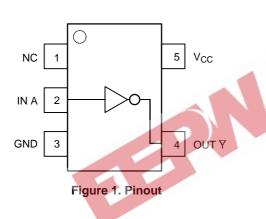
Single Unbuffered Inverter

The MC74HC1GU04 is a high speed CMOS unbuffered inverter fabricated with silicon gate CMOS technology.

The MC74HC1GU04 output drive current is 1/2 compared to MC74HC series.

- High Speed: $t_{PD} = 7$ ns (Typ) at $V_{CC} = 5$ V
- Low Power Dissipation: $I_{CC} = 1 \mu A$ (Max) at $T_A = 25 \degree C$
- High Noise Immunity
- Balanced Propagation Delays $(t_{pLH} = t_{pHL})$
- Symmetrical Output Impedance ($I_{OH} = I_{OL} = 2 \text{ mA}$)
- Chip Complexity: FET = 105
- Pb-Free Packages are Available



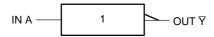
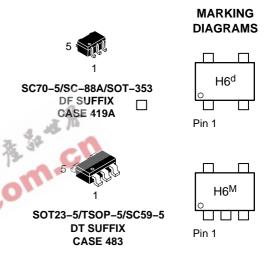


Figure 2. Logic Symbol



http://onsemi.com



PIN ASSIGNMENT					
1	NC				
2	IN A				
3	GND				
4	OUT \overline{Y}				
5	V _{CC}				

d = Date CodeM = Month Code

FUNCTION TABLE

Input A	Output \overline{Y}
L	Н
Н	L

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MAXIMUM RATINGS

Symbol		Parameter	Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to +7.0	V
V _{IN}	DC Input Voltage		-0.5 to $V_{CC} + 0.5$	V
V _{OUT}	DC Output Voltage		-0.5 to $V_{CC} + 0.5$	V
I _{IK}	DC Input Diode Current		±20	mA
lok	DC Output Diode Current		±20	mA
I _{OUT}	DC Output Sink Current		± 12.5	mA
I _{CC}	DC Supply Current per Supply Pin		±25	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case	for 10 Seconds	260	°C
TJ	Junction Temperature Under Bias		+ 150	°C
θ_{JA}	Thermal Resistance	SC70-5/SC-88A/SOT-353 (Note 1) SOT23-5/TSOP-5/SC59-5	350 230	°C/W
P _D	Power Dissipation in Still Air at 85°C	SC70-5/SC-88A/SOT-353 SOT23-5/TSOP-5/SC59-5	150 200	mW
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V _{ESD}	ESD Withstand Voltage	Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	> 2000 > 200 N/A	V
I _{LATCHUP}	Latchup Performance	Above V _{CC} and Below GND at 125°C (Note 5)	±500	mA

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace with no air flow.

- Tested to EIA/JESD22-A114-A.
- Tested to EIA/JESD22-A115-A.
- Tested to JESD22-C101-A.
- 5. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	DC Supply Voltage	2.0	6.0	V
V _{IN}	DC Input Voltage	0.0	V _{CC}	V
V _{OUT}	DC Output Voltage	0.0	V _{CC}	V
T _A	Operating Temperature Range	- 55	+ 125	°C
t _r , t _f	Input Rise and Fall Time $ \begin{array}{c} V_{CC} = 2.0 \ V \\ V_{CC} = 3.0 \ V \\ V_{CC} = 4.5 \ V \\ V_{CC} = 6.0 \ V \\ \end{array} $	0 0 0 0	1000 600 500 400	ns

DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

Junction Temperature °C	Time, Hours	Time, Years
80	1,032,200	117.8
90	419,300	47.9
100	178,700	20.4
110	79,600	9.4
120	37,000	4.2
130	17,800	2.0
140	8,900	1.0

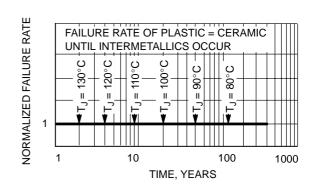


Figure 3. Failure Rate vs. Time Junction Temperature

DC ELECTRICAL CHARACTERISTICS

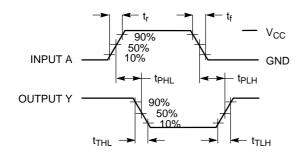
			v _{cc}	7	T _A = 25°C	;	T _A ≤	85°C	-55°C ≤ 1	T _A ≤ 125°C	
Symbol	Parameter	Test Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V _{IH}	Minimum High-Level Input Voltage		2.0 3.0 4.5 6.0	1.7 2.45 3.60 4.80			1.7 2.45 3.60 4.80		1.7 2.45 3.60 4.80		V
V _{IL}	Maximum Low-Level Input Voltage		2.0 3.0 4.5 6.0			0.3 0.5 0.9 1.20		0.3 0.5 0.9 1.20		0.3 0.5 0.9 1.20	V
V _{OH}	Minimum High–Level Output Voltage V _{IN} = V _{IH} or V _{IL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -20 \mu A$	2.0 3.0 4.5 6.0	1.8 2.7 4.0 5.5	2.0 3.0 4.5 5.9		1.8 2.7 4.0 5.5		1.8 2.7 4.0 5.5		٧
		$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -2 \text{ mA}$ $I_{OH} = -2.6 \text{ mA}$	4.5 6.0	4.18 5.68	4.33 5.76		4.13 5.63		4.08 5.58		
V _{OL}	Maximum Low–Level Output Voltage V _{IN} = V _{IH} or V _{IL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 20 \mu A$	2.0 3.0 4.5 6.0		0.0 0.0 0.0 0.0	0.1 0.1 0.1 0.1	39	0.1 0.1 0.1 0.1		0.1 0.1 0.1 0.1	٧
		$\begin{aligned} V_{IN} &= V_{IH} \text{ or } V_{IL} \\ I_{OL} &= 2 \text{ mA} \\ I_{OL} &= 2.6 \text{ mA} \end{aligned}$	4.5 6.0		20 3	0.26 0.26	¢	0.33 0.33		0.40 0.40	
I _{IN}	Maximum Input Leakage Current	V _{IN} = 6.0 V or GND	6.0			±0.1		±1.0		±1.0	μΑ
I _{CC}	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	6.0			1.0		10		40	μΑ

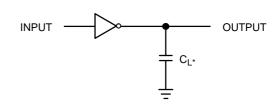
AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 6.0 \text{ ns}$)

			1	T _A = 25°C		$T_A \leq 85^{\circ}C$		$-55^{\circ}\text{C} \leq \text{T}_{\text{A}} \leq 125^{\circ}\text{C}$		
Symbol	Parameter	Test Conditions	Min	Тур	Max	Min	Max	Min	Max	Unit
t _{PLH} ,	Maximum	$V_{CC} = 5.0 \text{ V}$ $C_L = 15 \text{ pF}$		3	15		20		25	ns
t _{PHL}	Propagation Delay, Input A or B to \overline{Y}	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$		17 9 7 6.5	100 27 20 17		125 35 25 21		155 90 35 26	
t _{TLH} ,	Output Transition	$V_{CC} = 5.0 \text{ V}$ $C_L = 15 \text{ pF}$		4	10		15		20	ns
t _{THL}	Time	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		25 16 12 10	125 35 25 21		155 45 31 26		200 60 38 32	
C _{IN}	Maximum Input Capacitance			5	10		10		10	pF
						Typic	al @ 25°	°C, V _{CC} = 5.0	٧	

		Typical @ 25°C, V _{CC} = 5.0 V	
C_{PD}	Power Dissipation Capacitance (Note 6)	10	pF

^{6.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no–load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.





*Includes all probe and jig capacitance. A 1–MHz square input wave is recommended for propagation delay tests.

Figure 4. Switching Waveforms

Figure 5. Test Circuit

DEVICE ORDERING INFORMATION

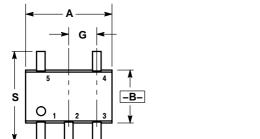
			Device Nome	enclature				
Device Order Number	Logic Circuit Indicator	Temp Range Identifier	Technology	Device Function	Package Suffix	Tape and Reel Suffix	Package Type	Tape and Reel Size [†]
MC74HC1GU04DFT1	MC	74	HC1G	U04	DE	T1	SC70-5/SC-88A/ SOT-353	178 mm (7 in) 3000 Unit
MC74HC1GU04DFT1G	MC	74	HC1G	U04	DF	T1	SC70-5/SC-88A/ SOT-353 (Pb-Free)	178 mm (7 in) 3000 Unit
MC74HC1GU04DFT2	MC	74	HC1G	U04	DF	T2	SC70-5/SC-88A/ SOT-353	178 mm (7 in) 3000 Unit
MC74HC1GU04DFT2G	MC	74	HC1G	U04	DF	T2	SC70-5/SC-88A/ SOT-353 (Pb-Free)	178 mm (7 in) 3000 Unit
MC74HC1GU04DTT1	MC	74	HC1G	U04	DT	T1	SOT23-5/TSOP-5/ SC59-5	178 mm (7 in) 3000 Unit
MC74HC1GU04DTT1G	MC	74	HC1G	U04	DT	T1	SOT23-5/TSOP-5/ SC59-5 (Pb-Free)	178 mm (7 in) 3000 Unit

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

SC70-5/SC-88A/SOT-353 **DF SUFFIX**

5-LEAD PACKAGE CASE 419A-02 ISSUE G



- NOTES:

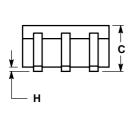
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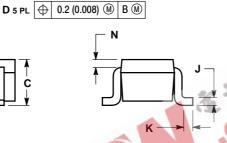
 2. CONTROLLING DIMENSION: INCH.

 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.

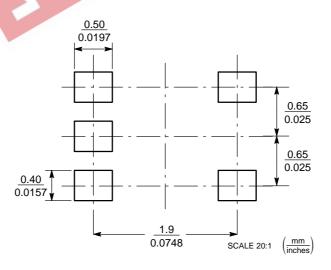
 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INC	HES	MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026	BSC	0.65	BSC
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008	REF	0.20	REF
S	0.079	0.087	2.00	2.20





SOLDERING FOOTPRINT*



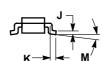
*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

SOT23-5/TSOP-5/SC59-5 **DT SUFFIX**

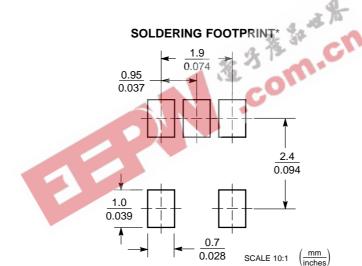
5-LEAD PACKAGE CASE 483-02 **ISSUE C**

0.05 (0.002)



- 1. DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.
- MAXIMUM LEAD THICKNESS INCLUDES
 LEAD FINISH THICKNESS. MINIMUM LEAD
 THICKNESS IS THE MINIMUM THICKNESS
 OF BASE MATERIAL.
 A AND B DIMENSIONS DO NOT INCLUDE
 MOLD FLASH, PROTRUSIONS, OR GATE
 PURPLE

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	2.90	3.10	0.1142	0.1220
В	1.30	1.70	0.0512	0.0669
С	0.90	1.10	0.0354	0.0433
D	0.25	0.50	0.0098	0.0197
G	0.85	1.05	0.0335	0.0413
Н	0.013	0.100	0.0005	0.0040
J	0.10	0.26	0.0040	0.0102
K	0.20	0.60	0.0079	0.0236
L	1.25	1.55	0.0493	0.0610
М	0	10	0	10
S	2.50	3.00	0.0985	0.1181



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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